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ectronic Version v1.1 desheet Version v1.			00 U.S.		
Title of Invention	BIPOLAR BOOTSTRAP TOP SWITCH GAT SEMICONDUCTOR POWER TOPOLOGIES		168		
Application Number: Date: First Named Applicant: Mi Confirmation Number:	r. Rick West				
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	Submitted by:	Elec. Sign.			
Mr. Will Whalen		ww	<b>-</b>		

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us-declaration

us-fee-sheet

us-request

application-body

## **Files**

Bootstrap-usdecl.xml

us-declaration.dtd

us-declaration.xsl

Bootstrap-usfees.xml

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Bootstrap-usrequ.xml

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Image7.tif
Image8.tif

Comments